

# 2SC1162

### 2.5A, 35V

### **NPN Plastic Encapsulated Transistor**

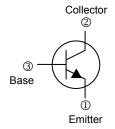
RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

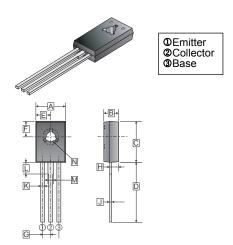
### **FEATURES**

• Low frequency power amplifier

## CLASSIFICATION OF h<sub>FE (1)</sub>

Product-Rank	2SC1162-B	2SC1162-C	2SC1162-D
Range	60~120	100~200	160~320





TO-126

REF.	Millimeter		REF.	Millimeter		
KEF.	Min. Max.	Min.		Max.		
Α	7.40	7.80	Н	1.10	1.50	
В	2.50	2.90	J	0.45	0.60	
С	10.60	11.00	K	0.66	0.86	
D	15.30	15.70	L	2.10	2.30	
Е	3.70	3.90	M	1.17	1.37	
F	3.90	4.10	N	3.00	3.20	
G	2.29 TYP.					

## **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V <sub>CBO</sub>	35	V
Collector to Emitter Voltage	$V_{CEO}$	35	V
Emitter to Base Voltage	$V_{EBO}$	5	V
Collector Current - Continuous	Ic	2.5	A
Collector Power Dissipation	Pc	750	mW
Junction, Storage Temperature	$T_{J}, T_{STG}$	150, -55~150	°C

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Collector to Base Breakdown Voltage	V <sub>(BR)CBO</sub>	35	-	-	V	I <sub>C</sub> =1mA, I <sub>E</sub> =0
Collector to Emitter Breakdown Voltage	$V_{(BR)CEO}$	35	-	-	V	I <sub>C</sub> =10mA, I <sub>B</sub> =0
Emitter to Base Breakdown Voltage	$V_{(BR)EBO}$	5	-	-	V	$I_E=1mA$ , $I_C=0$
Collector Cut – Off Current	I <sub>CBO</sub>	-	-	20	μΑ	$V_{CB}$ =35V, $I_E$ =0
Emitter Cut – Off Current	I <sub>EBO</sub>	-	-	20	μΑ	$V_{EB}$ =5 $V$ , $I_{C}$ =0
DC Current Cain	h <sub>FE (1)</sub>	60	-	320		$V_{CE}$ =2V, $I_{C}$ =0.5A
DC Current Gain	h <sub>FE (2)</sub>	20	-	-		V <sub>CE</sub> =2V, I <sub>C</sub> =1.5A*
Collector to Emitter Saturation Voltage	V <sub>CE(sat)</sub>	-	-	1	V	I <sub>C</sub> =2A, I <sub>B</sub> =200mA
Transition Frequency	f <sub>T</sub>	-	180	-	MHz	V <sub>CE</sub> =2V, I <sub>C</sub> =200mA
Collector Output Capacitance	$V_{BE}$	-	-	1.5	V	V <sub>CE</sub> =2V, I <sub>C</sub> =1.5A

<sup>\*</sup>Pulse test

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Any changes of specification will not be informed individually.

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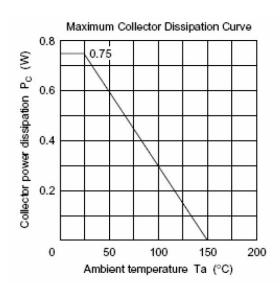


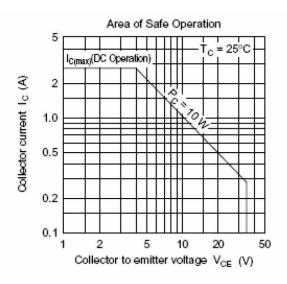
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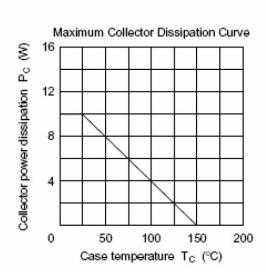
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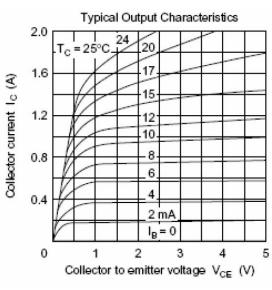
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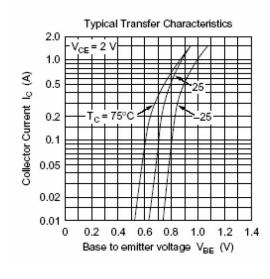
#### **CHARACTERISTIC CURVE**

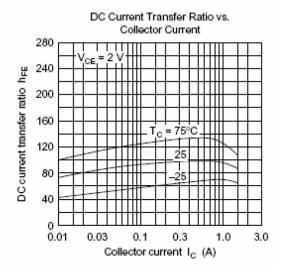












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